L Number	Hits		DB	Time stamp
-	12	(("6429063") or ("6417044") or ("6399441")	USPAT	2003/10/15 14:43
		or ("6395590") or ("6372564") or ("6346466")		
		or ("6255166") or ("6583007") or ("6566203") or ("6555427") or ("6518125") or		
		("6482708")).PN.		
_	2	((nitride adj read adj only adj memory) or	USPAT;	2003/09/02 14:33
		(nitride adj (read-only) adj memory)) and	US-PGPUB;	
		(ono same (wet adj etching) same (dop\$6 or	EPO; JPO;	
		implant\$6) same (buried adj bit adj line))	DERWENT;	
_	2	(ono same (wet adj etching) same (dop\$6 or	IBM_TDB USPAT;	2003/09/02 14:12
	_	implant\$6) same (buried adj bit adj line))	US-PGPUB;	2000,00,02 11.12
		and ((nitride adj read adj only adj memory)	EPO; JPO;	
		or (nitride adj (read-only) adj memory))	DERWENT;	
	3	//nitride and word and enly and memory) or	IBM_TDB	2002/00/02 14.15
-	3	((nitride adj read adj only adj memory) or (nitride adj (read-only) adj memory)) and	USPAT; US-PGPUB;	2003/09/02 14:15
		ono and (wet adj etching) and (dop\$6 or	EPO; JPO;	
•	·	implant\$6) and (buried adj bit adj line)	DERWENT;	
			IBM_TDB	
-	8	((nitride adj read adj only adj memory) or (nitride adj (read-only) adj memory)) and	USPAT; US-PGPUB;	2003/09/02 14:27
]		ono and (wet adj etching) and (dop\$6 or	EPO; JPO;	
		implant\$6) and (bit adj line)	DERWENT;	
			IBM_TDB	
-	94	((nitride adj read adj only adj memory) or	USPAT;	2003/09/02 14:33
		(nitride adj (read-only) adj memory)) and ono and (dop\$6 or implant\$6)	US-PGPUB; EPO; JPO;	
		and (depts of implantors)	DERWENT;	
			IBM_TDB	
-	94	(((nitride adj read adj only adj memory) or	USPAT;	2003/09/02 14:34
		(nitride adj (read-only) adj memory)) and ono and (dop\$6 or implant\$6)) and	US-PGPUB; EPO; JPO;	
		@ad<=20021115	DERWENT;	
			IBM_TDB	
-	81	((((nitride adj read adj only adj memory) or	USPAT;	2003/09/02 14:29
		(nitride adj (read-only) adj memory)) and ono and (dop\$6 or implant\$6)) and	US-PGPUB; EPO; JPO;	
		@ad<=20021115) and bit	DERWENT;	
			IBM_TDB	
-	72	((((nitride adj read adj only adj memory) or	USPAT;	2003/09/02 14:34
ĺ		(nitride adj (read-only) adj memory)) and ono and (dop\$6 or implant\$6)) and	US-PGPUB; EPO; JPO;	
		@ad<=20021115) and (bit adj line)	DERWENT;	
	_		IBM_TDB	
-	2	((nitride adj read adj only adj memory) or (nitride adj (read-only) adj memory) or	USPAT;	2003/09/02 14:33
		nrom) and (ono same (wet adj etching) same	US-PGPUB; EPO; JPO;	
		(dop\$6 or implant\$6) same (buried adj bit	DERWENT;	
		adj line))	IBM_TDB	
-	157	((nitride adj read adj only adj memory) or (nitride adj (read-only) adj memory) or	USPAT;	2003/09/02 14:33
ļ		NROM) and ono and (dop\$6 or implant\$6)	US-PGPUB; EPO; JPO;	
			DERWENT;	
		///	IBM_TDB	0000 (00 (00
-	150	(((nitride adj read adj only adj memory) or (nitride adj (read-only) adj memory) or	USPAT; US-PGPUB;	2003/09/02 14:34
		NROM) and ono and (dop\$6 or implant\$6)) and	EPO; JPO;	
		@ad<=20021115	DERWENT;	
	115	///mitmide and mand add and add area.	IBM_TDB	2002/00/00
-	115	<pre>((((nitride adj read adj only adj memory) or (nitride adj (read-only) adj memory) or</pre>	USPAT; US-PGPUB;	2003/09/02 14:46
		NROM) and ono and (dop\$6 or implant\$6)) and	EPO; JPO;	
		@ad<=20021115) and (bit adj line)	DERWENT;	
_		////nitrido add mand add andadd	IBM_TDB	2002/00/00 = : : :
-	85	<pre>(((((nitride adj read adj only adj memory) or (nitride adj (read-only) adj memory) or</pre>	USPAT; US-PGPUB;	2003/09/02 14:49
		NROM) and ono and (dop\$6 or implant\$6)) and	EPO; JPO;	
		@ad<=20021115) and (bit adj line)) and	DERWENT;	
		(etch\$5)	IBM_TDB	

-	24	(((((nitride adj read adj only adj memory) or (nitride adj (read-only) adj memory) or NROM) and ono and (dop\$6 or implant\$6)) and	USPAT; US-PGPUB; EPO; JPO;	2003/09/02 14:48
_	30	<pre>@ad<=20021115) and (bit adj line)) and (wet adj etch\$5) ((((nitride adj read adj only adj memory) or</pre>	DERWENT; IBM_TDB USPAT;	2003/09/02 14:47
		(nitride adj (read-only) adj memory) or NROM) and ono and (dop\$6 or implant\$6)) and @ad<=20021115) and (bur\$4 adj bit adj line)	US-PGPUB; EPO; JPO; DERWENT;	2003/03/02 14:47
-	6	((((((nitride adj read adj only adj memory) or (nitride adj (read-only) adj memory) or NROM) and ono and (dop\$6 or implant\$6)) and	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2003/09/02 14:47
-	6	@ad<=20021115) and (bit adj line)) and (wet adj etch\$5)) and (bur\$4 adj bit adj line) (((((nitride adj read adj only adj memory) or (nitride adj (read-only) adj memory) or NROM) and ono and (dop\$6 or implant\$6)) and @ad<=20021115) and (bur\$4 adj bit adj line))	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/09/02 14:49
-	26	and (wet adj etch\$5) (((((nitride adj read adj only adj memory) or (nitride adj (read-only) adj memory) or NROM) and ono and (dop\$6 or implant\$6)) and @ad<=20021115) and (bur\$4 adj bit adj line)) and (etch\$5)	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB	2003/09/03 07:57
-	99	((nitride adj read adj only adj memory) or (nitride adj (read-only) adj memory) or (NROM)) and ((ono or (oxide adj nitride adj oxide) or ((silicon adj oxide) adj (silicon adj nitride) adj (silicon adj oxide))) and (dop\$6 or implant\$6) and @ad<=20021115) and	USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB	2003/09/03 10:52
_	1	(bit adj line) and (word adj line) ("6566203").PN.	USPAT	2003/10/09 15:34
-	1	("6461906").PN.	USPAT	2003/09/03 13:17
-	329	("5496753").PN. (438/261).CCLS.	USPAT USPAT; US-PGPUB;	2003/09/03 13:07 2003/09/03 13:07
-	1390	(438/257).CCLS.	EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/09/03 13:09
-	578	(438/258).CCLS.	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/09/03 13:08
-	330	(438/259).CCLS.	IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/09/03 13:08
-	98	(438/260).CCLS.	IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2003/09/03 13:08
-	329	(438/261).CCLS.	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO;	2003/09/03 13:08
-	199	(438/262).CCLS.	DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT;	2003/09/03 13:08
L			IBM_TDB	

-	711	(438/526).CCLS.	USPAT;	2003/09/03 13:09
			US-PGPUB;	
			EPO; JPO;	
	1		DERWENT;	
			IBM_TDB	
-	694	(438/275).CCLS.	USPAT;	2003/09/03 13:09
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
		(100/001) 6676	IBM_TDB	/ /
-	246	(438/294).CCLS.	USPAT;	2003/09/03 13:10
			US-PGPUB;	
İ			EPO; JPO;	
			DERWENT; IBM TDB	
	152	(438/216).CCLS.	USPAT;	2003/09/03 13:10
1	152	(436/210).CCII3.	US-PGPUB;	2003/03/03 13:10
	İ		EPO; JPO;	
1			DERWENT;	
			IBM TDB	
_	333	(438/591).CCLS.	USPAT;	2003/09/03 13:10
			US-PGPUB;	=====
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	152	(438/216).CCLS.	USPAT;	2003/09/03 13:10
			US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
Ì			IBM_TDB	×
-	613	(438/264).CCLS.	USPAT;	2003/09/03 13:11
		•	US-PGPUB;	
			EPO; JPO;	İ
			DERWENT;	
	(36	(430/537) COLC	IBM_TDB	0000/00/00 10 10
_	636	(438/527).CCLS.	USPAT;	2003/09/03 13:12
			US-PGPUB; EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	750	(438/287).CCLS.	USPAT;	2003/09/03 13:12
		(333, 331, 733231	US-PGPUB;	2005, 05, 05
			EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	74	(438/954).CCLS.	USPAT;	2003/09/03 13:12
			US-PGPUB;	
	[EPO; JPO;	
	1		DERWENT;	
			IBM_TDB	
_	20	semiconductor same ono same (etch\$4 adj	USPAT;	2003/09/03 15:28
		stop)	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
_	20	 (semiconductor same ono same (etch\$4 adj	IBM_TDB USPAT;	2004/07/19 11:04
	20	stop)) and @ad<=20021115	US-PGPUB;	2004/0//19 11:04
1		Supply and sad-20021113	EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	480	semiconductor and ono and (etch adj stop)	USPAT;	2003/09/15 14:21
		and @ad<=20021115	US-PGPUB;	
			EPO; JPO;	
			DERWENT;	
			IBM_TDB	
-	12		USPAT;	2004/07/19 11:06
		stop) and @ad<=20021115	US-PGPUB;	
1			EPO; JPO;	
			DERWENT;	
L	L		IBM_TDB	

Sed<-20021115 US-PQPUB; DFO, JDO; DERWENT; DE					
- 397 257/\$.ccls. and one and (etch\$3 adj stop\$4 adj (layer or film)) and @ad<-2002115 - 340 438/\$.ccls. and one and (etch\$3 adj stop\$4 adj (layer or film)) and @ad<-2002115 - 502 one and (etch\$3 adj stop\$4 adj (layer or film)) and @ad<-2002115 - 502 one and (etch\$3 adj stop\$4 adj (layer or film)) and @ad<-2002115 - 9 (one game semiconductor same (etch\$3 adj stop\$4 adj (layer or film)) and @ad<-2002115 - 478 one and semiconductor and (etch\$3 adj stop\$4 adj (layer or film)) and @ad<-20021115 - 478 one and semiconductor and (etch\$3 adj stop\$4 adj (layer or film)) and @ad<-20021115 - 32968 liu.in. 32968 liu.in. - 10 liu.in. and cheng-jye - 10 liu.in. and cheng-jye - 2054 hsiung.in. - 2054 hsiung.in. and tai-liang - 32 chen.in. and chia-hsing - 32 chen.in. and chia-hsing - ("637531"), PN. ("9565203") or ("6416406") or ("639441") or ("6395500") or ("63955500") or ("6555300") or ("6555300") or ("6555520") or ("655	-	264		1	2003/09/03 15:38
2377 257/S, ccls. and one and (etch\$3 adj stop\$4 USPĀT, USP				DERWENT;	
### 1340 ### 138/\$.ccls. and one and (etch\$3 adj stop\$4 adj (layer or film)) and @ade=20021115 ### 1502	-	397		USPAT;	2003/09/15 14:52
340 438/s.ccls. and ono and (etch\$3 adj stop\$4 USPAT; 2003/09/15 14:52				EPO; JPO; DERWENT;	
- 502 ono and (etch\$3 adj stop\$4 adj (layer or film)) and @ad<=20021115 - 9 (ono same semiconductor same (etch\$3 adj USPAT, US-PGFUB; EPO; JPO; DERWENT, IBM_TDB USPAT, US-PGFUB; EPO; JPO; DERWENT,	-	340		USPAT;	2003/09/15 14:52
So2			adj (layer or film)) and @ad<=20021115	EPO; JPO; DERWENT;	
Second compared to the property of the prope	-	502		USPAT;	2003/09/15 14:53
- 9 (ono same semiconductor same (etch\$3 adj USPĀT; USPĀT) stop\$4 adj (layer or film))) and ead<=20021115 - 478 ono and semiconductor and (etch\$3 adj stop\$4 adj (layer or film)) and ead<=20021115 - 32968 liu.in. - 32968 liu.in. - 10 liu.in. and cheng-jye - 10 liu.in. and cheng-jye - 2054 hsiung.in. - 66294 chen.in. - 3 hsiung.in. and tai-liang - 3 hsiung.in. and chia-hsing - 3 chen.in. and chia-hsing - 3 ("6376341").PN. - 1 ("6376341").PN 1 ("6376341").PN 1 ("63765203") or ("6461906") or ("6399441") or ("6399590") or ("6372564") or ("6395590") or ("658125") or ("6366203") - 1 ("6275166") or ("6581205") or ("6366203") or ("658125") or ("6566203") or ("658125") or ("6566203") - 10 (Ju.in. and chia-hsing or ("6346466") or ("6329510") or ("6581205") or ("6366203") or ("631125") or ("6366203") or ("6581205") or ("6366203") or ("631125") or ("6361125") or ("6366203") or ("631125") or ("6366203") or ("6361125") or ("6366203") or ("6361125") or ("6361125") or ("6361125") or ("6366203") or ("6361125") or ("6361125") or ("636466") or ("636466") or ("6361125") or ("6361125") or ("6361125") or ("6361125") or ("6361125") or ("636466") or ("636466") or ("6366203") or ("6361125")		!		EPO; JPO; DERWENT;	
- 478 ono and semiconductor and (etch\$3 adj stop\$4 adj (layer or film)) and @ad<=20021115	-	9		USPAT;	2003/09/15 14:53
- 478 ono and semiconductor and (etch\$3 adj stop\$4			@ad<=20021115	DERWENT;	
- 32968 liu.in. - 10 liu.in. and cheng-jye - 2054 hsiung.in. - 2054 hsiung.in. - 66294 chen.in. - 3 hsiung.in. and tai-liang - 3 chen.in. and chia-hsing - 3 ("6376341").PN. ("6366203") or ("6461906") or ("6395441") or ("63955427") or ("6518255") or ("6556203") or ("6555427") or ("6556203") or ("6556203") or ("6555427") or ("6556203") or ("6566203") or ("6556203") or ("656	-	478		USPAT; US-PGPUB;	2003/09/15 15:34
- 32968 liu.in. - 10 liu.in. and cheng-jye - 2054 hsiung.in. - 66294 chen.in. - 3 hsiung.in. and tai-liang - 32 chen.in. and chia-hsing - 1 ("6376341").PN. ("6566203") or ("6461906") or ("63955427") or ("6383007") or ("6388203") or ("65556203") or ("6555527") or ("65556203") or ("65556203") or ("65556203") or ("6382008") or ("6382008") - 10 liu.in. and cheng-jye USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT; USPAT USPAT 2003/10/10 11:29 2003/09/15 15:36				DERWENT;	
- 10 liu.in. and cheng-jye USPAT; US-PGPUB; EPO, JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO, JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO, JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO, JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO, JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO, JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO, JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO, JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO, JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO, JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO, JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO, JPO; DERWENT; IBM_TDB USPAT; USPAT US	-	32968	liu.in.	USPAT; US-PGPUB;	2003/09/15 15:36
- 10 liu.in. and cheng-jye				DERWENT;	
- 2054 hsiung.in. - 66294 chen.in. - 66294 chen.in. - 3 hsiung.in. and tai-liang - 3 chen.in. and chia-hsing - 1 ("6376341").PN 3 (("6566203") or ("6461906") or ("598753")].PN 13 (("6429063") or ("6417044") or ("6399441") or ("6395590") or ("6375564") or ("6346466") or ("6555427") or ("65558207") or ("65583007") or ("6346466") or ("65556207") or ("65558207") or ("6482708") - 2 2003/09/15 15:36 - 2003/09/15 15:37 - 3 2003/09/15 15:37 - 3 3 3 3 3 3 3 3 3 3 3 3 3 3 3 3 3 3	-	10	liu.in. and cheng-jye	USPAT; US-PGPUB;	2003/09/15 15:35
US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM TDB USPAT 2003/10/10 11:29 ("6376341").PN. 1 ("6376341").PN. ("646203") or ("6461906") or ("6399441") USPAT 2003/10/10 10:48 ("5496753")).PN. 13 ("6429063") or ("6417044") or ("6399441") or ("6395590") or ("6555166") or ("65883007") or ("6346466") or ("63666203") or ("6555427") or ("6566203") or ("66566203") or ("6566203") or ("6585167") or ("65883007") or ("6482708")				DERWENT;	
DERWENT; IBM TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EFO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EFO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EFO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT USPAT 2003/09/15 15:37 USPAT 2003/10/10 11:29 USPAT 2003/10/10 10:48 USPAT 2003/10/10 10:48 USPAT 2003/10/10 10:48 USPAT 2003/10/10 10:48 USPAT 2003/10/10 10:48 USPAT 2003/10/10 10:48 USPAT 2003/10/10 10:48 USPAT 2003/10/15 14:49 USPAT 2003/10	-	2054	hsiung.in.	US-PGPUB;	2003/09/15 15:36
US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT USPAT 2003/10/10 11:29 ("65466203") or ("6417044") or ("6399441") or ("5496753")).PN. 13 (("65656203") or ("6417044") or ("6399441") or ("6395590") or ("6372564") or ("6346466") or ("6555166") or ("6555166") or ("6566203") or ("6566203") or ("6555166") or ("65583007") or ("6566203") or ("6555427") or ("6518125") or ("6482708")				DERWENT;	
DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT USPAT 2003/10/10 11:29 2003/10/10 10:48 USPAT 2003/10/10 10:48 USPAT 2003/10/15 14:49 Or ("6395590") or ("6372564") or ("6399441") or ("6255166") or ("6388007") or ("63464666") or ("6255166") or ("65883007") or ("6566203") or ("6555427") or ("6518125") or ("6482708")	-	66294	chen.in.	US-PGPUB;	2003/09/15 15:36
US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT 2003/09/15 15:37 US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT 2003/10/10 11:29 USPAT 2003/10/10 10:48 ("5496753")).PN. - 13 (("6429063") or ("6417044") or ("6399441") or ("6395590") or ("6417044") or ("6399441") or ("6255166") or ("6583007") or ("6346466") or ("6255166") or ("6583007") or ("6566203") or ("6555427") or ("6518125") or ("6482708")		li .		DERWENT;	
- 32 chen.in. and chia-hsing chen.in. and chia-hsing chen.in. and chia-hsing chen.in. and chia-hsing DERWENT; IBM_TDB USPAT; US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT 2003/10/10 11:29 USPAT 2003/10/10 10:48 ("6429063") or ("6417044") or ("6399441") or ("6395590") or ("6372564") or ("6346466") or ("6255166") or ("6583007") or ("6566203") or ("6555427") or ("6518125") or ("6482708")	-	. 3	hsiung.in. and tai-liang	US-PGPUB;	2003/09/15 15:37
US-PGPUB; EPO; JPO; DERWENT; IBM_TDB USPAT 2003/10/10 11:29 ("6566203") or ("6461906") or ("5496753")).PN. - 13 (("6429063") or ("6417044") or ("6399441") or ("6395590") or ("6372564") or ("6346466") or ("6255166") or ("6583007") or ("6566203") or ("6555427") or ("6518125") or ("6482708")				DERWENT; IBM_TDB	
DERWENT; IBM_TDB USPAT U	-	32	chen.in. and chia-hsing	US-PGPUB;	2003/09/15 15:37
- 3 (("6566203") or ("6461906") or ("5496753")).PN. - 13 (("6429063") or ("6417044") or ("6399441") or ("6395590") or ("6372564") or ("6346466") or ("6255166") or ("6583007") or ("6566203") or ("6555427") or ("6518125") or ("6482708")				DERWENT; IBM_TDB	
- 13 (("6429063") or ("6417044") or ("6399441") USPAT 2003/10/15 14:49 or ("6395590") or ("6372564") or ("6346466") or ("6255166") or ("6583007") or ("6566203") or ("6555427") or ("6518125") or ("6482708")	-		(("6566203") or ("6461906") or		
or ("6555427") or ("6518125") or ("6482708")	-	13	(("6429063") or ("6417044") or ("6399441") or ("6395590") or ("6372564") or ("6346466")	USPAT	2003/10/15 14:49
OI ("63/6341"/).PN.			or ("6255166") or ("6583007") or ("6566203") or ("6555427") or ("6518125") or ("6482708") or ("6376341")).PN.		

-	14	· · · · · · · · · · · · · · · · · · ·	USPAT	2003/10/16 09:22
		or ("6395590") or ("6372564") or ("6346466")		
		or ("6255166") or ("6583007") or ("6566203")		*
		or ("6555427") or ("6518125") or ("6482708")		
		or ("6376341") or ("6538270")).PN.		
-	2	(("6433384") or ("6472701")).PN.	USPAT	2004/07/19 13:20
-	65	("ONO") same (masking or protect\$5) same	USPAT;	2003/10/16 09:47
		((silicon adj nitride) or ("SiN")) same	US-PGPUB;	
		(pattern\$6 or (wet adj etch\$6))	EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	63	("ONO") same (masking or protect\$5) same	USPAT;	2004/07/19 11:07
]		((silicon adj nitride) or ("SiN")) same	US-PGPUB;	
		(pattern\$6 or (wet adj etch\$6)) and	EPO; JPO;	
		@ad<=20021115	DERWENT:	
			IBM TDB	
-	128	(semiconductor same ono same ((etch\$4 adj	USPAT;	2004/07/19 11:05
		stop) or (protect\$6))) and @ad<=20021115	US-PGPUB;	
	İ		EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	21	(semiconductor same ono same (etch\$4 adj	USPAT;	2004/07/19 11:05
		stop)) and @ad<=20021115	US-PGPUB;	,,
		Joseph, and can consider	EPO; JPO;	
			DERWENT;	
			IBM TDB	
_	13	438/287,261,591.ccls. and ono and (etch adj	USPAT;	2004/07/19 11:06
		stop) and @ad<=20021115	US-PGPUB;	,,
		F ,	EPO; JPO;	
			DERWENT;	
			IBM TDB	
-	75	("ONO") same (masking or protect\$5) same	USPAT;	2004/07/19 11:07
		((silicon adj nitride) or ("SiN")) same	US-PGPUB;	=====, ==, ==========================
	1	(pattern\$6 or (wet adj etch\$6)) and	EPO; JPO;	
		@ad<=20021115	DERWENT;	
			IBM TDB	
-	83	(((oxide adj nitride adj oxide) or ("ONO"))	USPAT;	2004/07/19 12:50
		same (masking or protect\$5) same ((silicon	US-PGPUB;	====, ==, ==
		adj nitride) or ("SiN")) same (pattern\$6 or	EPO; JPO;	
		(wet adj etch\$6))) and @ad<=20021115	DERWENT;	
		,	IBM TDB	
_	5	("5652173" "5801100" "6030877"	USPAT	2004/07/19 12:41
		"6054329" "6309922").PN.]
_	5	("5652173" "5801100" "6030877"	USPAT	2004/07/19 12:47
1		"6054329" "6309922").PN.	33	1 2001,07,15 12.47
-	1		USPAT	2004/07/19 13:20
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